# imall

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## Contact us

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### Switching Diode Array Steering Diode TVS Array<sup>™</sup>

#### DESCRIPTION

These low capacitance diode arrays are multiple, discrete, isolated junctions fabricated by a planar process and mounted in a 14-Pin SOIC package for use as steering diodes protecting up to eight I/O ports from ESD, EFT, or surge by directing them either to the positive side of the power supply line or to ground (see Figure 1). An external TVS diode may be added between the positive supply line and ground to prevent overvoltage on the supply rail. They may also be used in fast switching core-driver applications. This includes computers and peripheral equipment such as magnetic cores, thin-film memories, plated-wire memories, etc., as well as decoding or encoding applications. These arrays offer many advantages of integrated circuits such as high-density packaging and improved reliability. This is a result of fewer pick and place operations, smaller footprint, smaller weight, and elimination of various discrete packages that may not be as user friendly in PC board mounting. They are available with either tin-lead plating terminations or as RoHS compliant with annealed matte-tin finish.

Important: For the latest information, visit our website http://www.microsemi.com.

#### FEATURES

- 16-diode array protects 8 lines
- Molded 14-Pin SOIC package
- UL 94V-0 flammability classification
- Low capacitance
- Switching speeds less than 5 ns
- IEC 61000-4 compatible:

61000-4-2 (ESD): Air 15 kV, contact – 8 kV 61000-4-4 (EFT): 40 A – 5/50 ns

61000-4-5 (surge): 12 A, 8/20 μs

• RoHS compliant device is available

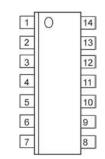
#### **APPLICATIONS / BENEFITS**

- Protection from switching transients and induced RF
- Low capacitance steering diode protection for high frequency data lines
- Ideal for:

RS-232 & RS-422 Interface Networks. Ethernet: 10 Base T Computer I / O Ports LAN Switching Core Drivers



### 14-Pin Package



Top Viewing Pin Layout

#### MSC – Lawrence

6 Lake Street, Lawrence, MA 01841 Tel: 1-800-446-1158 or (978) 620-2600 Fax: (978) 689-0803

#### MSC – Ireland

Gort Road Business Park, Ennis, Co. Clare, Ireland Tel: +353 (0) 65 6840044 Fax: +353 (0) 65 6822298

Website: www.microsemi.com



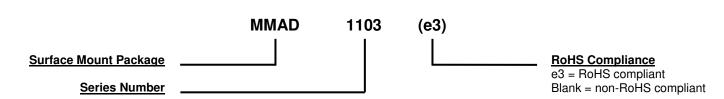
#### MAXIMUM RATINGS

Parameters/Test Conditions	Symbol	Value	Unit
Junction and Storage Temperature	$T_J$ and $T_{STG}$	-55 to +150	°C/W
Peak Working Reverse Voltage	V <sub>RWM</sub>	75	V
Repetitive Peak Forward Current (one diode)	I <sub>FRM</sub>	400	mA
Forward Surge Current @ 8.3 ms	I <sub>FSM</sub>	2	Α
@ 8/20 μs		12	
Rated Average Power Dissipation (total package)	P <sub>M(AV)</sub>	1500	mW
Solder Temperature @ 10 s		260	°C

#### **MECHANICAL and PACKAGING**

- CASE: Void-free transfer molded thermosetting epoxy body meeting UL94V-0 flammability classification.
- TERMINALS: Tin-lead or RoHS compliant annealed matte-tin plating solderable per MIL-STD-750 method 2026.
- MARKING: MSC logo, MMAD1103 or MMAD1103e3 and date code. Pin #1 is to the left of the dot or indent on top of package.
- DELIVERY option: Tape and reel or carrier tube. Consult factory for quantities.
- WEIGHT: Approximately 0.127 grams
- See <u>Package Dimensions</u> on last page.

#### PART NOMENCLATURE



SYMBOLS & DEFINITIONS				
Symbol	Definition			
Ст	Total Capacitance: The total small signal capacitance between the diode terminals of a complete device.			
I <sub>R</sub>	Maximum Leakage Current: The maximum leakage current that will flow at the specified voltage and temperature.			
V <sub>(BR)</sub>	Breakdown Voltage: The voltage across the device at a specified current I(BR) in the breakdown region.			
VF	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.			
V <sub>RWM</sub>	Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range.			

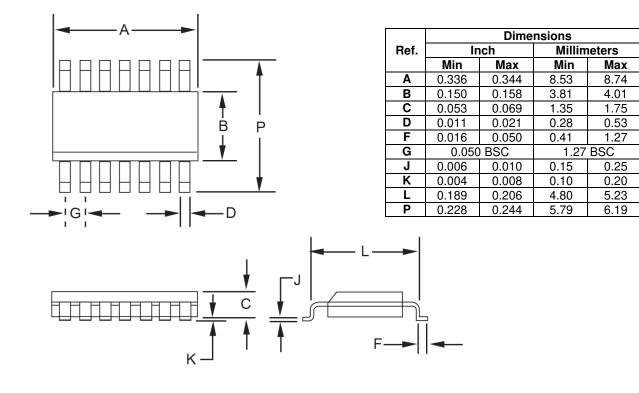
#### ELECTRICAL CHARACTERISTICS @ 25 °C unless otherwise stated

PART NUMBER	BREAKDOWN VOLTAGE V <sub>(BR)</sub> @ I <sub>BR</sub> =100 μA V	LEAK CURF Ir T <sub>A</sub> = 2	RENT 25 °C	LEAK CURI Ι Τ <sub>A</sub> = 1	RENT R 50 °C	TOTAL CAPACITANCE C <sub>T</sub> @ 0 V pF	REVERSE RECOVERY TIME t <sub>rr</sub> ns	FORWARD VOLTAGE V <sub>F</sub> I <sub>F</sub> = 10 mA V	FORWARD VOLTAGE V <sub>F</sub> I <sub>F</sub> = 100 mA V
	MIN	MAX	$@V_{R}$	MAX	@V <sub>R</sub>	TYP (Note 1)	МАХ	MAX	МАХ
MMAD1103 MMAD1103e3	90	0.200	20	300	20	1.5	5.0	1.00	1.20

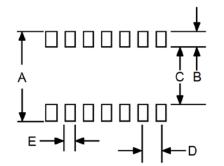
NOTE 1: Individual diode capacitance is less than 1.5 pF but will read higher between pins with the connected parallel diode array shown.



#### **PACKAGE DIMENSIONS**



PAD LAYOUT

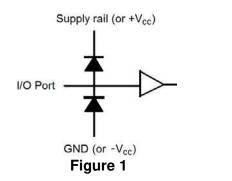


	Dimensions				
Ref.	Inch	Millimeters			
	Typical	Typical			
Α	0.275	6.99			
В	0.060	1.52			
С	0.144	3.94			
D	0.050	1.27			
Е	0.024	0.61			

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#### SCHEMATIC AND CIRCUIT



RF01063, Rev B (2/17/14)